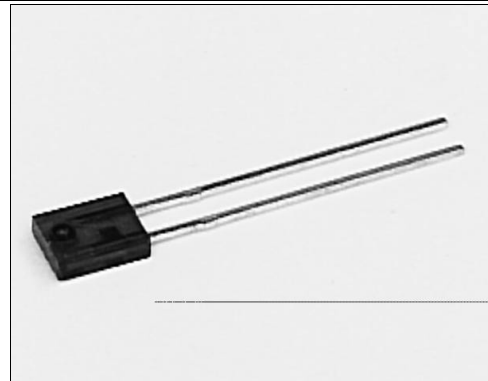


SEP8506

GaAs Infrared Emitting Diode

FEATURES

- Side-emitting plastic package
- 50° (nominal) beam angle
- 935 nm wavelength
- Mechanically and spectrally matched to SDP8406 phototransistor, SDP8106 photodarlington and SDP8000/8600 series Schmitt trigger



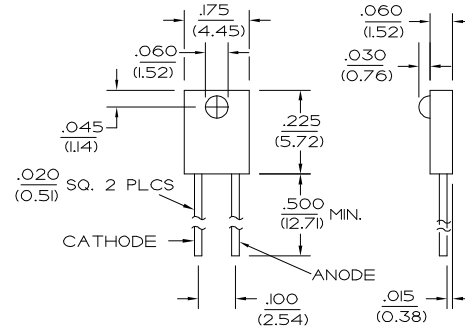
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DESCRIPTION

The SEP8506 is a gallium arsenide infrared emitting diode molded in a side-emitting red plastic package. The chip is positioned to emit radiation through a plastic lens from the side of the package.

OUTLINE DIMENSIONS in inches (mm)

Tolerance	3 plc decimals	±0.005(0.12)
	2 plc decimals	±0.020(0.51)



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SEP8506

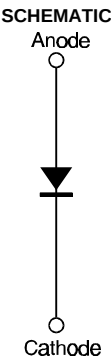
GaAs Infrared Emitting Diode

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)						
PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Irradiance ⁽¹⁾	H				mW/cm ²	I _F =20 mA
SEP8506-001		0.05		0.36		
SEP8506-002		0.33		0.52		
SEP8506-003		0.45		0.90		
Forward Voltage	V _F			1.5	V	I _F =20 mA
Reverse Breakdown Voltage	V _{BR}	3.0			V	I _R =10 μA
Peak Output Wavelength	λ _p		935		nm	
Spectral Bandwidth	Δλ		50		nm	
Spectral Shift With Temperature	Δλ _p /ΔT		0.3		nm/°C	
Beam Angle ⁽²⁾	Ø		50		degr.	I _F =Constant
Radiation Rise And Fall Time	t _r , t _f		0.7		μs	

- Notes
- Measured in mW/cm² into a 0.104 (2.64) diameter aperture placed 0.535 (13.6) from the lens tip.
 - Beam angle is defined as the total included angle between the half intensity points.

ABSOLUTE MAXIMUM RATINGS	
(25°C Free-Air Temperature unless otherwise noted)	
Continuous Forward Current	50 mA
Power Dissipation	100 mW ⁽¹⁾
Storage Temperature Range	-40°C to 85°C
Operating Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C

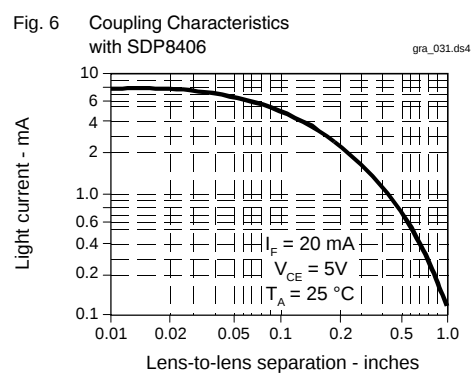
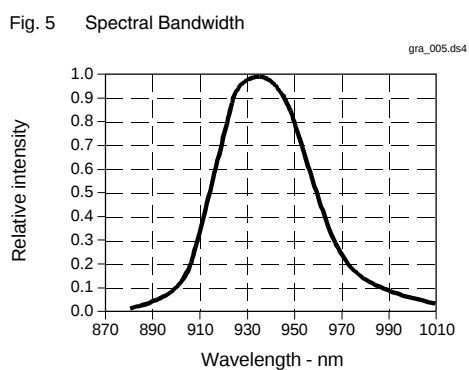
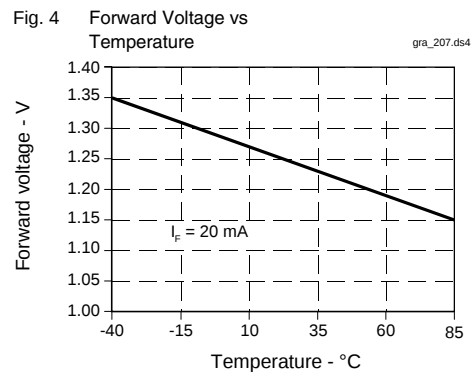
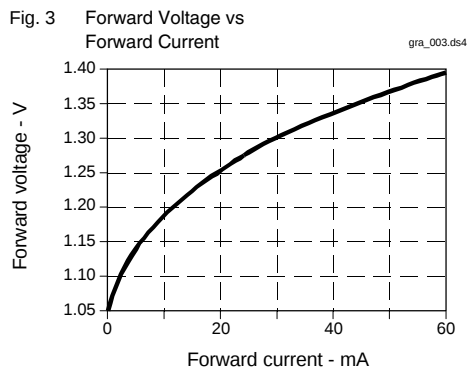
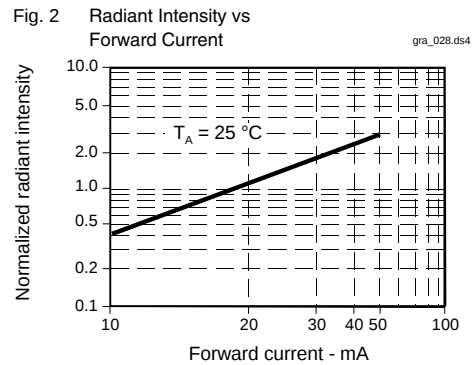
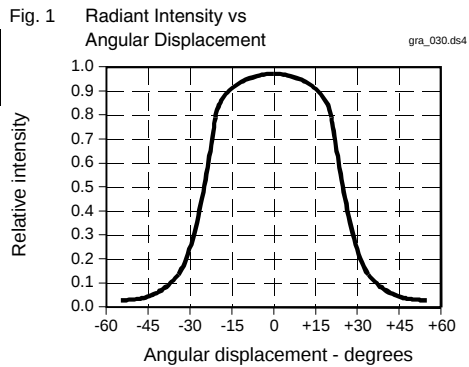
- Notes
- Derate linearly from 25°C free-air temperature at the rate of 0.78 mW/°C.



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

SEP8506

GaAs Infrared Emitting Diode

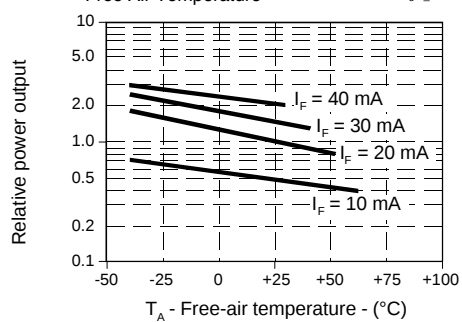


SEP8506

GaAs Infrared Emitting Diode

Fig. 7 Relative Power Output vs
Free Air Temperature

gra_130.ds4



All Performance Curves Show Typical Values